



25V PNP LOW SATURATION TRANSISTOR IN SOT23

Features

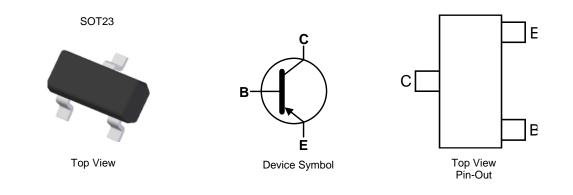
- BV_{CEO} > -25V
- BV_{CEO} > -35V forward blocking voltage
- I_C = -3A Continuous Collector Current
- Low Saturation Voltage, V_{CE(SAT)} < -150mV @ -1A.
- R_{CE(sat)} = 87mΩ for a low equivalent on-resistance
- 725mW power dissipation
- hFE characterised up to -6A for high current gain hold-up
- Complementary NPN Type: ZXTN649F
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads
- Solderable per MIL-STD-202, Method 208
- Weight 0.008 grams (Approximate)

Application

- MOSFET Gate Drivers
- Power Switching in Automotive and Industrial Applications
- Motor Drive and Control



Ordering Information (Note 4)

| Product | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|------------|---------|--------------------|-----------------|-------------------|
| ZXTP749FTA | 1N8 | 7 | 8 | 3,000 |

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

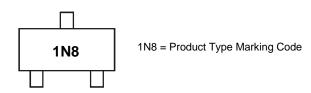
 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | -35 | V |
| Collector-Emitter Voltage | VCEO | -25 | V |
| Emitter-Base Voltage | V _{EBO} | -7 | V |
| Continuous Collector Current | Ιc | -3 | A |
| Peak Pulse Current | ICM | -6 | A |
| Base Current | IB | -500 | mA |
| Peak Pulse Current | I _{BM} | -2 | A |

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|------------------|-------------|------|
| Power Dissipation (Note 5) | PD | 725 | mW |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{0JA} | 172 | °C/W |
| Thermal Resistance, Junction to Leads (Note 6) | R _{θJL} | 79 | °C/W |
| Operating and Storage Temperature Range | TJ, TSTG | -55 to +150 | °C |

ESD Ratings (Note 7)

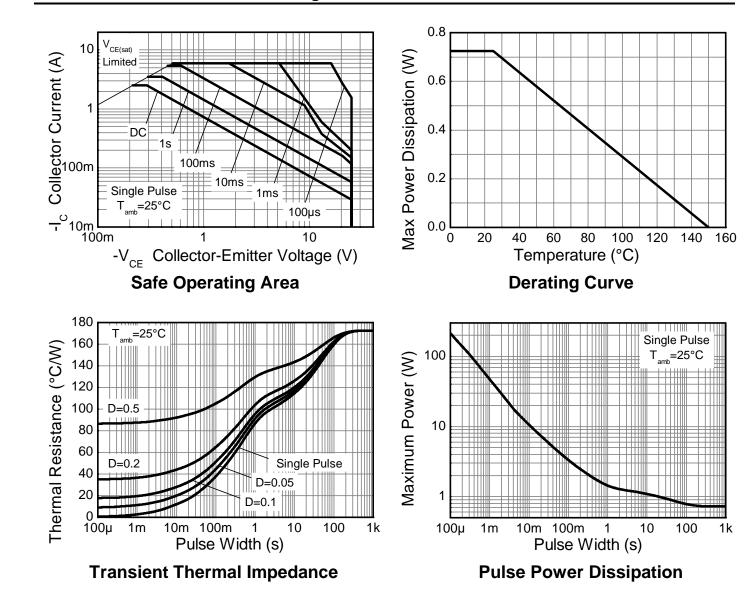
| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | ЗA |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | С |

 5. For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1 oz. copper, in still air conditions; the device is measured when operating in a steady-state condition.
6. Thermal resistance from junction to solder-point (at the end of the collector lead).
7. Refer to JEDEC specification JESD22-A114 and JESD22-A115. Notes:



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Thermal Characteristics and Derating information



ZXTP749F Document Number: DS31901 Rev. 4 - 2



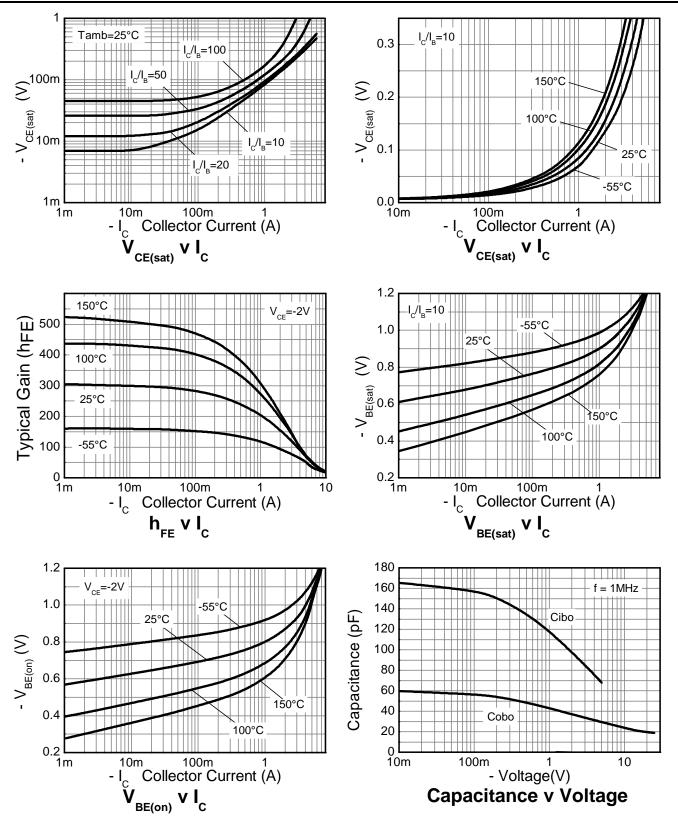
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|--|----------------------|-------------------------|-------------------------|--------------------|----------|--|
| Collector-Base Breakdown Voltage | BV _{CBO} | -35 | -60 | - | V | $I_{\rm C} = -100 \mu {\rm A}$ |
| Collector-Emitter Breakdown Voltage (Note 8) | BVCEO | -25 | -40 | - | V | I _C = -10mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -7 | -8.4 | - | V | I _E = -100μA |
| Collector Cutoff Current | I _{CBO} | - | <1 | -50 | nA | $V_{CB} = -28V$ |
| Emitter Cutoff Current | I _{EBO} | - | <1 | -0.5 -50 | μA nA | $V_{CB} = -28V, T_A = +100^{\circ}C$ $V_{EB} = -5.6V$ |
| Static Forward Current Transfer Ratio (Note 8) | hFE | 200 130 100 25 | 320 230 180 50 | 500 - - - | - | |
| Collector-Emitter Saturation Voltage (Note 8) | V _{CE(sat)} | - | -85 -229 | -150 -350 | mV | $I_{C} = -1A, I_{B} = -100mA$ $I_{C} = -3A, I_{B} = -300mA$ |
| Base-Emitter Turn-On Voltage (Note 8) | V _{BE(on)} | - | -786 | -850 | mV | $I_{C} = -1A, V_{CE} = -2V$ |
| Base-Emitter Saturation Voltage (Note 8) | V _{BE(sat)} | - | -895 | -1,000 | mV | $I_{\rm C} = -1A, I_{\rm B} = -100 \text{mA}$ |

Notes: 8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



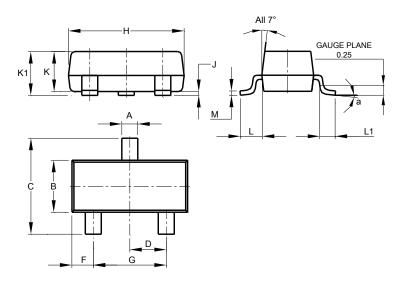
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

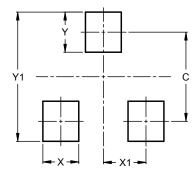
Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.



| | SOT23 | | | | | |
|-----|----------------------|-------|-------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 0.37 | 0.51 | 0.40 | | | |
| В | 1.20 | 1.40 | 1.30 | | | |
| c | 2.30 | 2.50 | 2.40 | | | |
| D | 0.89 | 1.03 | 0.915 | | | |
| F | 0.45 | 0.60 | 0.535 | | | |
| G | 1.78 | 2.05 | 1.83 | | | |
| Н | 2.80 | 3.00 | 2.90 | | | |
| J | 0.013 | 0.10 | 0.05 | | | |
| κ | 0.890 | 1.00 | 0.975 | | | |
| K1 | 0.903 | 1.10 | 1.025 | | | |
| L | 0.45 | 0.61 | 0.55 | | | |
| L1 | 0.25 | 0.55 | 0.40 | | | |
| М | 0.085 | 0.150 | 0.110 | | | |
| а | 0° | 8° | | | | |
| All | All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) | |
|------------|---------------|--|
| С | 2.0 | |
| Х | 0.8 | |
| X1 | 1.35 | |
| Y | 0.9 | |
| Y1 | 2.9 | |



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